

[查询RM600DY-66S供应商](#)

PRELIMINARY
Notice: This is not a final specification.
Some parametric limits are subject to change.

HVDi (High Voltage Diode) Module

捷多邦，专业PCB打样工厂，24小时加急出货

MITSUBISHI FAST RECOVERY DIODE MODULE

RM600DY-66S

HIGH POWER, HIGH SPEED SWITCHING USE
INSULATED TYPE

RM600DY-66S



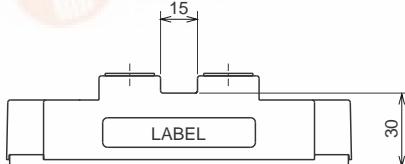
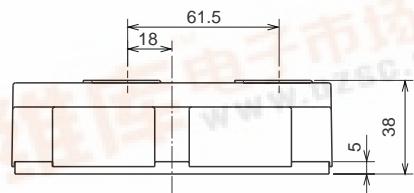
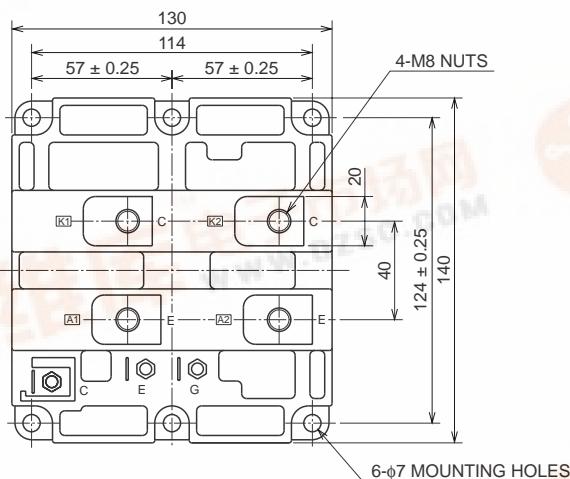
- IDC 600A
- VRRM 3300V
- Insulated type
- 2-element in a pack

APPLICATION

3-level inverters, 3-level converters, DC choppers.

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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**HIGH POWER, HIGH SPEED SWITCHING USE
INSULATED TYPE**

ABSOLUTE MAXIMUM RATINGS ($T_j = 25^\circ\text{C}$)

| Symbol | Parameter | Voltage class | Unit |
|--------------------|-------------------------------------|---------------|------|
| | | 66 | |
| V _{RRM} | Repetitive peak reverse voltage | 3300 | V |
| V _{DRM} | Non-repetitive peak reverse voltage | 3300 | V |
| V _{R(DC)} | Reverse DC voltage | 2200 | V |

| Symbol | Parameter | Conditions | Ratings | Unit |
|------------------|--|---|------------------------|------------------|
| I _{DC} | DC current | T _C = 25°C | 600 | A |
| I _{FMS} | Surge (non-repetitive) forward current | 1 cycle of half wave 60Hz, peak value, T _j = 25°C start, VRM = 0V | 4800 | A |
| I ² t | I ² t for fusing | Value of one cycle surge current, t _w = 8.3ms, T _j = 25°C start | 9.60 × 10 ⁴ | A ² s |
| T _j | Junction temperature | — | -40 ~ +150 | °C |
| T _{stg} | Storage temperature | — | -40 ~ +125 | °C |
| V _{iso} | Isolation Voltage | Main terminal to case, 60Hz, sinusoidal, AC, 1min, rms | 6000 | V |
| — | Mounting torque | Main terminals screw : M6 | 6.67 ~ 8.24 | N · m |
| — | | Mounting screw : M6 | 2.84 ~ 3.43 | N · m |
| — | Weight | Typical value | 1.5 | kg |

ELECTRICAL CHARACTERISTICS ($T_j = 25^\circ\text{C}$)

| Symbol | Parameter | Test conditions | Limits | | | Unit |
|----------------------|----------------------------|--|--------|-------|-------|------|
| | | | Min | Typ | Max | |
| I _{RRM} | Repetitive reverse current | V _{RRM} applied, VRM = V _{RRM} | — | — | 4 | mA |
| V _{FM} | Forward voltage | I _{FM} = 600A, t _w ≤ 1ms | — | 3.30 | 4.29 | V |
| t _{rr} | Reverse recovery time | I _{FM} = 600A, dI/dt = -1200A/μs, | — | — | 1.20 | μs |
| Q _{rr} | Reverse recovery charge | VR = 1650V | — | 150 | — | μC |
| R _{th(j-c)} | Thermal resistance | Junction to case (Per 1/2 module) | — | — | 0.048 | °C/W |
| R _{th(c-f)} | Contact thermal resistance | Case to fin, thermal grease applied (Per 1/2 module) | — | 0.024 | — | °C/W |